# imall

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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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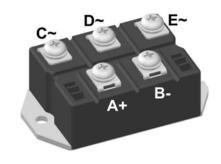


## **Standard Rectifier Module**

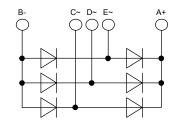
3~ Rectifier Bridge

Part number VUO160-08NO7

R	3~ Rectifier					
$V_{RRM}$	=	800 V				
$\mathbf{I}_{DAV}$	=	175 A				
$\mathbf{I}_{FSM}$	=	1800 A				



**E**72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### **Applications:**

- Diode for main rectification
- For three phase bridge configurations
  Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: PWS-E

- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

### VUO160-08NO7

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## VUO160-08NO7

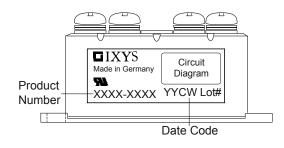
Rectifier	r				Ratings	3	
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse bloc	king voltage	$T_{VJ} = 25^{\circ}C$			900	V
V <sub>RRM</sub>	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			800	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 800 V	$T_{VJ} = 25^{\circ}C$			200	μA
		$V_{R}$ = 800 V	$T_{VJ} = 150^{\circ}C$			2	mA
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 60 A	$T_{VJ} = 25^{\circ}C$			1.10	V
		I <sub>F</sub> = 180 A				1.40	V
		$I_{F} = 60 \text{ A}$	T <sub>vJ</sub> =125 °C			1.00	V
		I <sub>F</sub> = 180 A				1.39	V
DAV	bridge output current	T <sub>c</sub> = 110°C	T <sub>vJ</sub> = 150°C			175	A
		rectangular d = ⅓					
V <sub>F0</sub>	threshold voltage		T <sub>vj</sub> = 150°C			0.77	V
r <sub>F</sub>	slope resistance } for power	loss calculation only				3.4	mΩ
R <sub>thJC</sub>	thermal resistance junction to ca	ise				0.5	K/W
R <sub>thCH</sub>	thermal resistance case to heats	sink			0.2		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			250	W
IFSM	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			1.80	kA
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.95	kA
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 150°C			1.53	kA
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.65	kA
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			16.2	kA²s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			15.7	kA²s
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 150°C			11.7	kA²s
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			11.3	kA²s
C	junction capacitance	V <sub>R</sub> = 400 V; f = 1 MHz	$T_{VJ} = 25^{\circ}C$		35		pF

IXYS reserves the right to change limits, conditions and dimensions.

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Package PWS-E			Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit
	RMS current	per terminal				200	Α
T <sub>stg</sub>	storage temperature			-40		125	°C
T <sub>vj</sub>	virtual junction temperature			-40		150	°C
Weight					284		g
M <sub>D</sub>	mounting torque			4.25		5.75	Nm
M <sub>T</sub>	terminal torque			4.25		5.75	Nm
d <sub>Spp/App</sub>	creepage distance on surface   striking distance through air		terminal to terminal	12.0			mm
d <sub>Spb/Apb</sub>			terminal to backside	26.0			mm
	isolation voltage	t = 1 second		3000			V
1002	t = 1 minute		50/60 Hz, RMS; Iıso∟ ≤ 1 mA	2500			V



Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO160-08NO7	VUO160-08NO7	Box	5	462438

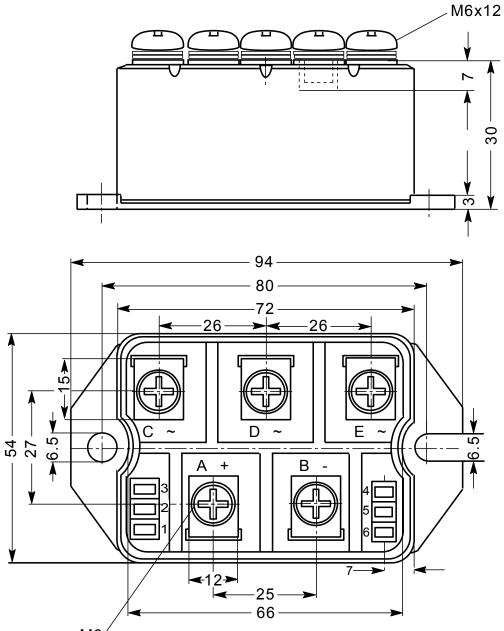
Equiva	lent Circuits for	Simulation	* on die level	T <sub>vJ</sub> = 150 °C
	)[R₀	Rectifier		
V <sub>0 max</sub>	threshold voltage	0.77		V
$R_{0 max}$	slope resistance *	2.2		mΩ

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## VUO160-08NO7

### **Outlines PWS-E**





B- C- D- E- A+

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### VUO160-08NO7

#### Rectifier

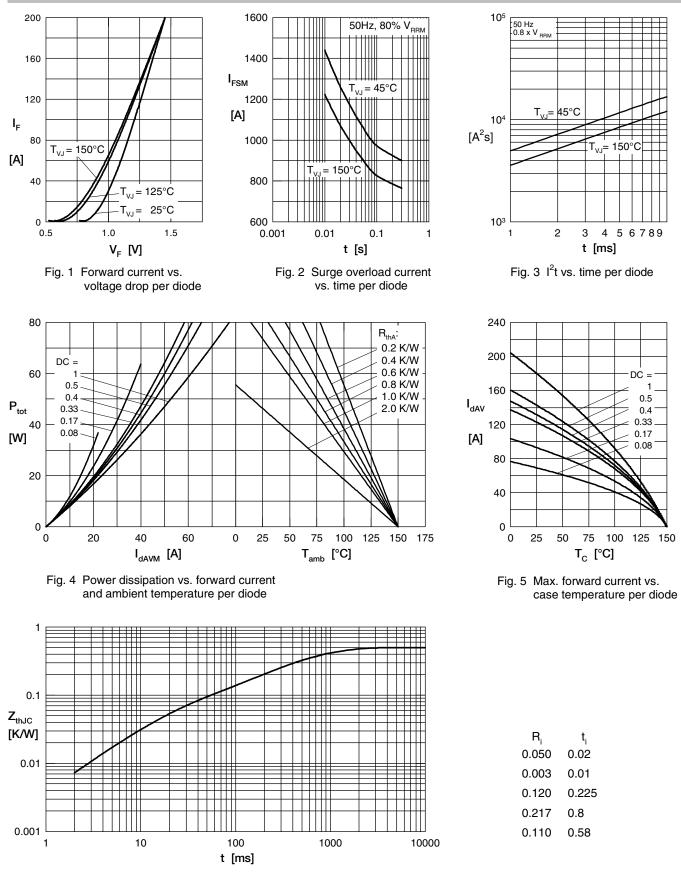


Fig. 6 Transient thermal impedance junction to case vs. time per diode

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